

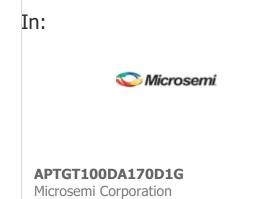


APTGT100DA120T1G	
APTGT100DA120T1G	
Microsemi	
IGBT 1200V 140A 480W SP1	
1.APTGT100DA120T1G.pdf	
2.APTGT100DA120T1G.pdf	
RoHS Lead free / RoHS	
Compliant New original, 2650 pcs Stock Available.	
Hong Kong	
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See specs for product details.

Specifications	
Part Number	APTGT100DA120T1G
Manufacturer	Microsemi
Description	IGBT 1200V 140A 480W SP1
Category	Discrete Semiconductor Products > Transistors - IGBTs -
Part Status	2650 pcs Stock
Voltage - Collector Emitter Breakdown (Max)	1200V
Vce(on) (Max) @ Vge, Ic	2.1V @ 15V, 100A
Supplier Device Package	SP1
Series	-
Power - Max	480W
Package / Case	SP1
Operating Temperature	-40°C ~ 150°C (TJ)
NTC Thermistor	Yes
Mounting Type	Chassis Mount
Input Capacitance (Cies) @ Vce	7.2nF @ 25V
Input	Standard
IGBT Type	Trench Field Stop
Current - Collector Cutoff (Max)	250μΑ
Current - Collector (Ic) (Max)	140A
Configuration	Single

## You May Be Also Be interested



IGBT 1700V 200A 695W D1



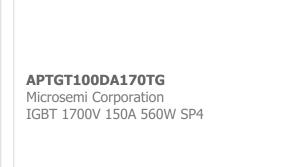
**APTGT100A602G** 

Microsemi Corporation

MOD IGBT 600V 150A SP2



🝑 Microsemi.



Microsemi.









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ADD:Unit A5-B5 No.509, 5/F Sing Win Factory Building, 15-17 Shing yip St, Kwun Tong, Kowloon, HongKong.

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